NSN 5962-01-377-1124

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View Online at https://aerobasegroup.com/nsn/5962-01-377-1124

view Offilite at https://defobasegroup.com/nsi//0302-01-01/1-112-4
Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
0.217 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Ultraviolet erasable and programmed and high impedance and w/enable and w/disable and w/inhibit
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
11 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
120.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
6.00 input picofarads and 12.00 output picofarads
Time Rating Per Chacteristic:
250.00 nanoseconds access
Memory Device Type:
Eprom
Test Data Document:
$96906 \hbox{-mil-std-883 standard (includes industry or association standards, \ individual manufactureer standards, \ etc.)}.$
Terminal Type And Quantity:
28 printed circuit
Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

Fiig:

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